

STTH6010-Y

Automotive ultrafast recovery - high voltage diode

Features

- AEC-Q101 qualified
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- ECOPACK[®]2 compliant component

Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability like automotive applications.

These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.

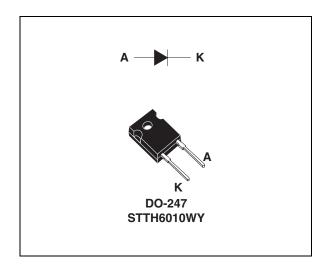


Table 1. Device summary

| I _{F(AV)} | 60 A | | |
|-----------------------|--------|--|--|
| V _{RRM} | 1000 V | | |
| T _j | 175 °C | | |
| V _F (typ) | 1.3 V | | |
| t _{rr} (typ) | 49 ns | | |

Characteristics Device name or AN #

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

| Symbol | Pa | Value | Unit | | |
|---------------------|---|--|------|-----|---|
| V_{RRM} | Repetitive peak reverse voltage | Repetitive peak reverse voltage | | | |
| I _{F(RMS)} | Forward rms current | | | 80 | Α |
| I _{F(AV)} | Average forward current, $\delta = 0.5$ | Average forward current, δ = 0.5 T_c = 75 °C | | | |
| I _{FRM} | Repetitive peak forward current | Repetitive peak forward current $t_p = 5 \mu s$, $F = 5 kHz square$ | | 450 | Α |
| I _{FSM} | Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$ | | | | Α |
| T _{stg} | Storage temperature range | -65 to +175 | °C | | |
| T _j | Operating junction temperature range | -40 to +175 | °C | | |

Table 3. Thermal parameters

| Symbol | Parameter | Value | Unit |
|----------------------|------------------|-------|------|
| R _{th(j-c)} | Junction to case | 0.78 | °C/W |

Table 4. Static electrical characteristics

| Symbol | Parameter | Test conditions | | Min. | Тур | Max. | Unit |
|-------------------------------|-------------------------|---|-----------------------|------|-----|------|------|
| I _R ⁽¹⁾ | Poverse leekage ourrent | T _j = 25 °C | V - V | | | 20 | |
| R`′ | Reverse leakage current | current $T_j = 125 ^{\circ}\text{C}$ $V_R = V_{RRM}$ | | 20 | 200 | μΑ | |
| | | T _j = 25 °C | | | | 2.0 | |
| V _F ⁽²⁾ | Forward voltage drop | T _j = 100 °C | I _F = 60 A | | 1.4 | 1.8 | V |
| | | T _j = 150 °C | | | 1.3 | 1.7 | |

- 1. Pulse test: t_p = 5 ms, δ < 2 %
- 2. Pulse test: t_p = 380 μ s, δ < 2 %

To evaluate the conduction losses use the following equation:

$$P = 1.3 \text{ x } I_{F(AV)} + 0.0067 I_{F}^{2}_{(RMS)}$$

Device name or AN # Characteristics

Table 5. Dynamic characteristics

| Symbol | Parameter | Test conditions | Min. | Тур | Max. | Unit |
|-----------------|--------------------------|--|------|-----|------|------|
| | | $I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$ | | | 115 | |
| t _{rr} | Reverse recovery time | $I_F = 1 \text{ A, } dI_F/dt = -100 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$ | | 61 | 80 | ns |
| | | $I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25 \text{ °C}$ | | 49 | 65 | |
| I _{RM} | Reverse recovery current | $I_F = 60 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s}, \ V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$ | | 31 | 40 | Α |
| S | Softness factor | $I_F = 60 \text{ A}, dI_F/dt = -200 \text{ A/}\mu\text{s}, \ V_R = 600 \text{ V}, T_j = 125 ^{\circ}\text{C}$ | | 1 | | |
| t _{fr} | Forward recovery time | $I_F = 60 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_{FR} = 1.5 \text{ x } V_{Fmax}, T_j = 25 \text{ °C}$ | | | 750 | ns |
| V _{FP} | Forward recovery voltage | $I_F = 60 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s},$ $T_j = 25 ^{\circ}\text{C}$ | | 4 | | ٧ |

Figure 1. Conduction losses versus average current

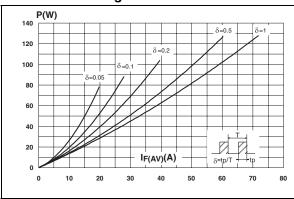


Figure 2. Forward voltage drop versus forward current

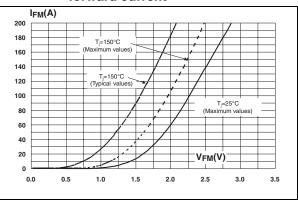


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

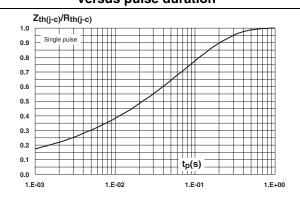
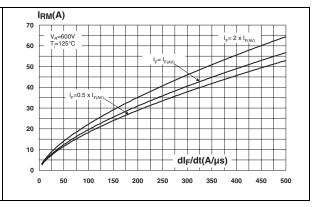


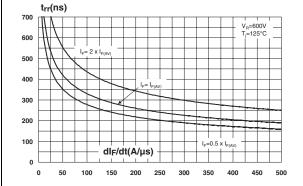
Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)



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Figure 5. Reverse recovery time versus dl_F/dt (typical values)

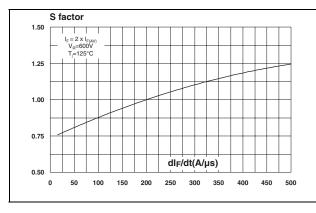
Figure 6. Reverse recovery charges versus dl_F/dt (typical values) Q_{rr}(µC) 10 V_R=600V T_j=125°C I_F= 2 x I_F

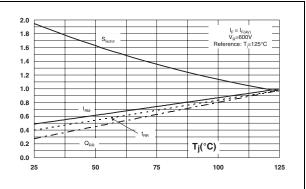


5 I_E=0.5 x I_{Ε(Δ)} 3 2 dlf/dt(A/µs)

Figure 7. Softness factor versus dl_F/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature





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Figure 9. Transient peak forward voltage versus dl_F/dt (typical values)

Figure 10. Forward recovery time versus dl_F/dt (typical values)

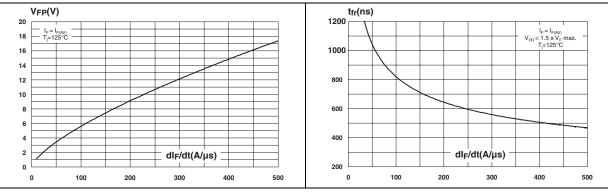
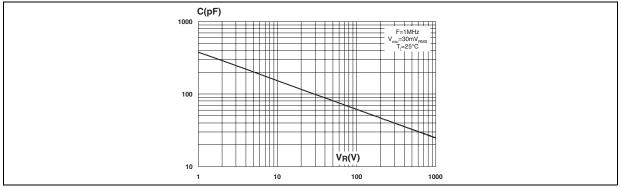


Figure 11. Junction capacitance versus reverse voltage applied (typical values)



2 Package information

Epoxy meets UL94, V0

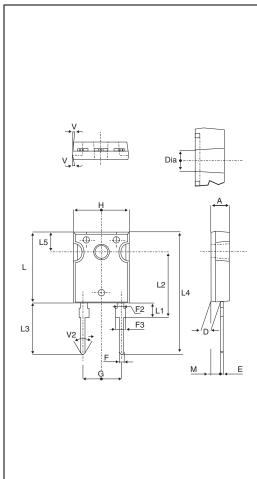
• Cooling method: by conduction (C)

Recommended torque value: 0.80 N⋅m

Maximum torque value: 1.0 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. DO-247 dimensions



| | Dimensions | | | | | |
|------|-------------|-------|-------|-------|--------|-------|
| Ref. | Millimeters | | rs | | Inches | |
| | Min. | | Max | Min. | | Max. |
| Α | 4.85 | | 5.15 | 0.191 | | 0.203 |
| D | 2.20 | | 2.60 | 0.086 | | 0.102 |
| E | 0.40 | | 0.80 | 0.015 | | 0.031 |
| F | 1.00 | | 1.40 | 0.039 | | 0.055 |
| F2 | | 2.00 | | | 0.078 | |
| F3 | 2.00 | | 2.40 | 0.078 | | 0.094 |
| G | | 10.90 | | | 0.429 | |
| Н | 15.45 | | 15.75 | 0.608 | | 0.620 |
| Ш | 19.85 | | 20.15 | 0.781 | | 0.793 |
| L1 | 3.70 | | 4.30 | 0.145 | | 0.169 |
| L2 | | 18.50 | | | 0.728 | |
| L3 | 14.20 | | 14.80 | 0.559 | | 0.582 |
| L4 | | 34.60 | | | 1.362 | |
| L5 | | 5.50 | | | 0.216 | |
| М | 2.00 | | 3.00 | 0.078 | | 0.118 |
| V | | 5° | | | 5° | |
| V2 | | 60° | | | 60° | |
| Dia. | 3.55 | | 3.65 | 0.139 | | 0.143 |

3 Ordering information

Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty | Delivery mode |
|------------|------------|---------|--------|----------|---------------|
| STTH6010WY | STTH6010WY | DO-247 | 4.4 g | 30 | Tube |

4 Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 04-Nov-2011 | 1 | Initial release. |

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